



# 20V P-CHANNEL ENHANCEMENT MODE MOSFET POWERDI®

### **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>C</sub> = +25°C		
-20V	$6.7 \text{m}\Omega$ @ $V_{GS} = -4.5V$	-40A		
-200	9.0mΩ @ V <sub>GS</sub> = -2.5V	-40A		

#### **Description**

This MOSFET has been designed to minimize the on-state resistance  $(R_{DS(on)})$  and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

#### **Applications**

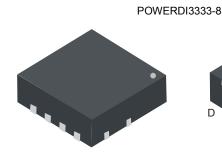
- Load Switch
- Power Management Functions

#### **Features**

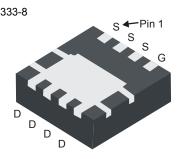
- Low R<sub>DS(ON)</sub> ensures on state losses are minimized
- Small form factor thermally efficient package enables higher density end products
- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product
- ESD HBM protected up to 1KV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 standards for High Reliability

#### **Mechanical Data**

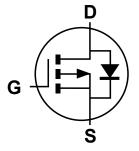
- Case: POWERDI3333-8
- Case Material: Molded Plastic, "Green" Molding Compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See diagram
- Terminals: Finish Matte Tin annealed over Copper leadframe.
  Solderable per MIL-STD-202, Method 208 <sup>®</sup>
- Weight: 0.008 grams (approximate)







**Bottom View** 



**Equivalent Circuit** 

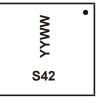
#### **Ordering Information** (Note 4)

Part Number	Case	Packaging
DMP26M7UFG-7	POWERDI3333-8	2000/Tape & Reel
DMP26M7UFG-13	POWERDI3333-8	3000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



947

S42 or S47= Product Type Marking Code YYWW = Date Code Marking YY = Last digit of year (ex: 14 = 2014) WW = Week code (01 ~ 53)



# **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Drain-Source Voltage	V <sub>DSS</sub>	-20	V		
Gate-Source Voltage	$V_{GSS}$	±10	V		
Continuous Drain Current (Note 5) V <sub>GS</sub> = -4.5V Steady State T <sub>A</sub> = +70°		$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$ $T_C = +25^{\circ}C$	$I_{D}$	-18.0 -14.5 -40	Α
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I <sub>DM</sub>	-80	Α		
Maximum Continuous Body Diode Forward Current (Note 5)			Is	-2.2	Α
Avalanche Current (Note 7) L=0.1mH			I <sub>AS</sub>	-23	Α
Avalanche Energy (Note 7) L=0.1mH	E <sub>AS</sub>	28	mJ		

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Total Bower Dissinction (Note 5)	T <sub>A</sub> = +25°C	ם	2.3	- W
Total Power Dissipation (Note 5)	T <sub>C</sub> = +25°C	$P_{D}$	41	
Thermal Resistance, Junction to Ambient	(Note 5)	D	54	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	136	
Thermal Resistance, Junction to Case	$R_{ heta JC}$	3.0		
Operating and Storage Temperature Range	$T_{J_i}T_{STG}$	-55 to +150	°C	

### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

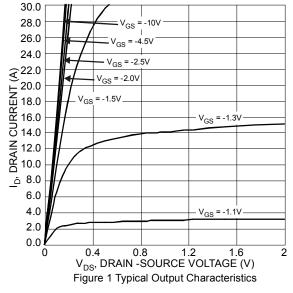
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-20	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	-1	μΑ	$V_{DS} = -16V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 8V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)	ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	-0.4	I	-1.0	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
		1	4.0	6.7		$V_{GS} = -4.5V$ , $I_{D} = -15A$	
Static Drain-Source On-Resistance	R <sub>DS (ON)</sub>	l	5.0	9.0	mΩ	$V_{GS} = -2.5V$ , $I_{D} = -10A$	
		-	7	_		$V_{GS} = -1.8V, I_{D} = -1A$	
Diode Forward Voltage	$V_{SD}$	_	-0.7	-1.2	V	$V_{GS} = 0V, I_{S} = -10A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss		5404	_		V <sub>DS</sub> = -10V, V <sub>GS</sub> = 0V f = 1.0MHz	
Output Capacitance	Coss	_	728	_	pF		
Reverse Transfer Capacitance	Crss	-	612	_			
Gate Resistance	R <sub>G</sub>		3.8	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V <sub>GS</sub> = -4.5V)	$Q_g$	l	64	_			
Total Gate Charge (V <sub>GS</sub> = -10V)	Qg		140	_	nC	$V_{DD} = -10V, I_D = -20A$	
Gate-Source Charge	$Q_{gs}$	1	8.5	_	IIC	V <sub>DD</sub> = -10V, I <sub>D</sub> = -20A	
Gate-Drain Charge	$Q_{gd}$		17	_			
Turn-On Delay Time	t <sub>D(on)</sub>	_	9.1	_			
Turn-On Rise Time	t <sub>r</sub>	_	19	_	20	$V_{GS} = -4.5V, V_{DD} = -10V,$	
Turn-Off Delay Time	$t_{D(off)}$	_	146	_	ns	$R_G = 1\Omega$ , $R_G = 1\Omega$ , $I_D = -10A$	
Turn-Off Fall Time	t <sub>f</sub>	_	104	_			
Reverse Recovery Time	t <sub>rr</sub>		61	_	ns	I <sub>F</sub> = -10A, di/dt = 100A/μs	
Reverse Recovery Charge	Qrr	_	44	_	nC	$I_F = -10A$ , di/dt = $100A/\mu s$	

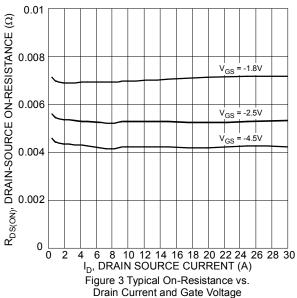
Notes:

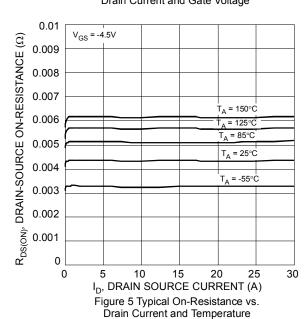
- 5. R<sub>θJA</sub> is determined with the device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. R<sub>θJC</sub> is guaranteed by design while R<sub>θJA</sub> is determined by the user's board design.
- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
- 7 .UIS in production with L =0.1mH,  $T_J$  = +25°C
- 8. Short duration pulse test used to minimize self-heating effect.
- 9. Guaranteed by design. Not subject to product testing.

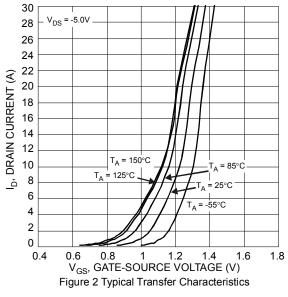


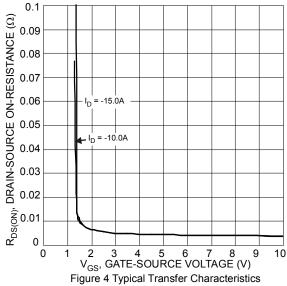












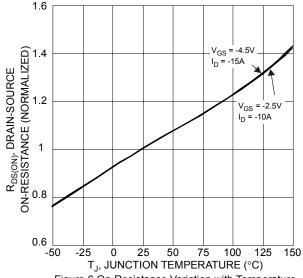
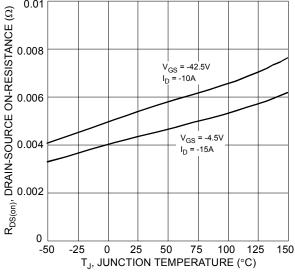
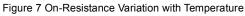


Figure 6 On-Resistance Variation with Temperature









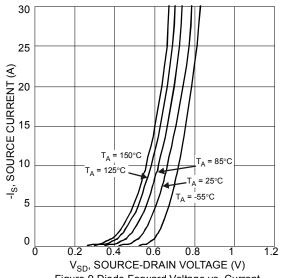
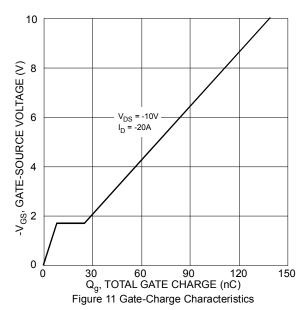


Figure 9 Diode Forward Voltage vs. Current



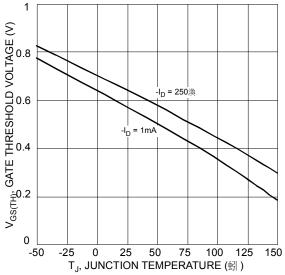
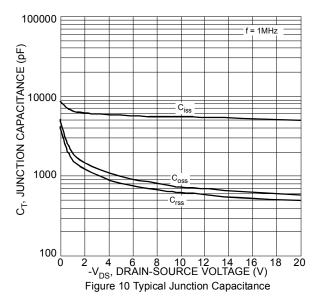
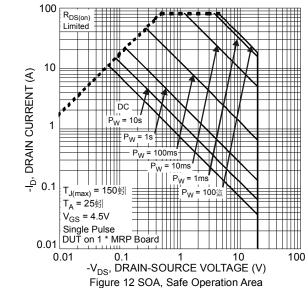
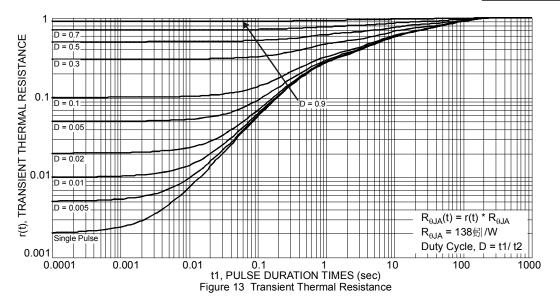


Figure 8 Gate Threshold Variation vs. Ambient Temperature



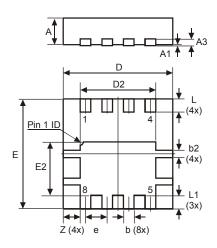






## **Package Outline Dimensions**

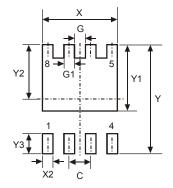
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



POWERDI3333-8					
Dim	Min	Max	Тур		
D	3.25	3.35	3.30		
Е	3.25	3.35	3.30		
D2	2.22	2.32	2.27		
E2	1.56	1.66	1.61		
Α	0.75	0.85	0.80		
A1	0	0.05	0.02		
<b>A3</b>	_	_	0.203		
b	0.27	0.37	0.32		
b2	_	_	0.20		
L	0.35	0.45	0.40		
L1	_	_	0.39		
е	_	_	0.65		
Z	_	_	0.515		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)				
С	0.650				
G	0.230				
G1	0.420				
Υ	3.700				
Y1	2.250				
Y2	1.850				
Y3	0.700				
X	2.370				
X2	0.420				



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